NSN 5961-01-017-6033

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-017-6033 **Inclosure Material:** Glass and metal **Overall Length:** 0.475 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.562 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 off-state voltage, peak **Current Rating Per Characteristic:** 100.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 115.0 degrees celsius junction **Terminal Type And Quantity:** 2 tab, solder lug and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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